NSN 5961-01-129-2851

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-129-2851 **Inclosure Material:** Glass and metal **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 reverse voltage, peak **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug or 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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